



# **PNP Silicon Small Signal Transistor**

Qualified per MIL-PRF-19500/382

<u>Qualified Levels:</u> JAN, JANTX, and JANTXV

### **DESCRIPTION**

This 2N2944A through 2N2946A PNP silicon transistor device is military qualified up to a JANTXV level for high-reliability applications. Microsemi also offers numerous other products to meet higher and lower power voltage regulation applications.

Important: For the latest information, visit our website <a href="http://www.microsemi.com">http://www.microsemi.com</a>.

#### **FEATURES**

- JEDEC registered 2N2944A thru 2N2946A series.
- JAN, JANTX, and JANTXV qualifications per MIL-PRF-19500/382 available.
- RoHS compliant versions available (commercial grade only).

TO-46 (TO-206AB) Package

## Also available in:

UB package
(surface mount)
2N2944AUB – 2N2946AUB

## **APPLICATIONS / BENEFITS**

- · Low profile metal can package.
- ESD to Class 3 per MIL-STD-750, method 1020.

### MAXIMUM RATINGS @ +25 °C unless specified otherwise.

Parameters/Test Conditions		Symbol	Value	Unit
Junction and Storage Temperature		$T_J$ and $T_{STG}$	-65 to +200	°C
Thermal Resistance Junction-to-Ambier	nt	R <sub>OJA</sub>	435	°C/W
Collector Current (dc)		I <sub>C</sub>	-100	mA
Emitter to Base voltage (static),	2N2944A	$V_{EBO}$	-15	V
collector open	2N2945A		-25	
	2N2946A		-40	
Collector to Base voltage (static),	2N2944A	$V_{CBO}$	-15	V
emitter open	2N2945A		-25	
	2N2946A		-40	
Collector to Emitter voltage (static),	2N2944A	$V_{\sf CEO}$	-10	V
base open	2N2945A		-20	
	2N2946A		-35	
Emitter to Collector voltage	2N2944A	$V_{ECO}$	-10	V
	2N2945A		-20	
	2N2946A		-35	
Total Power Dissipation, all terminals @ T <sub>A</sub> = +25 °C <sup>(1)</sup>		$P_T$	400	mW

**Notes:** 1. Derate linearly 2.30 mW /°C above  $T_A = +25$  °C.

### MSC - Lawrence

6 Lake Street, Lawrence, MA 01841 Tel: 1-800-446-1158 or (978) 620-2600

Fax: (978) 689-0803

#### MSC - Ireland

Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 Fax: +353 (0) 65 6822298

#### Website:

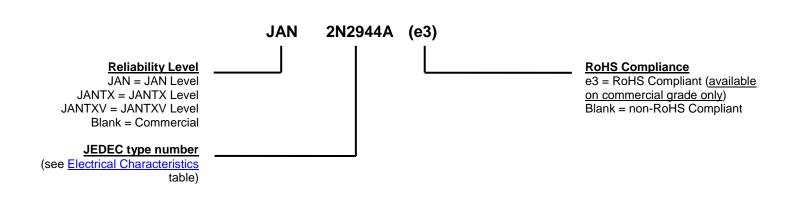
www.microsemi.com



## **MECHANICAL and PACKAGING**

- CASE: Nickel plated kovar, glass seals.
- TERMINALS: Gold plating over nickel, solder dipped, kovar.
- MARKING: Part number, date code, manufacturer's ID.
- WEIGHT: 0.234 grams.
- See Package Dimensions on last page.

### **PART NOMENCLATURE**



	SYMBOLS & DEFINITIONS				
Symbol	Definition				
I <sub>B</sub>	Base current (dc).				
Ι <sub>Ε</sub>	Emitter current (dc).				
$V_{CB}$	Collector to base voltage (dc).				
$V_{EB}$	Emitter to base voltage (dc).				
$V_{(BR)}$	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.				



## **ELECTRICAL CHARACTERISTICS** @ 25 °C unless otherwise noted.

Characteristic		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS:		- Cymbol	141111	Maxi	Omit
Collector-Emitter Breakdown Voltage					
I <sub>C</sub> = -10 μA	2N2944A 2N2945A 2N2946A	V(BR)CEO	-10 -20 -35		V
Emitter-Collector Breakdown Voltage					
I <sub>E</sub> = -10 μA, I <sub>B</sub> = 0	2N2944A 2N2945A 2N2946A	V(BR)ECO	-10 -20 -35		V
Collector-Base Cutoff Current					
VCB = -15 V	2N2944A	ICBO	10		μΑ
VCB = -25 V	2N2945A		10		
Vcb = -40 V	2N2946A		10		
Emitter-Base Cutoff Current		l==o		0.4	
VEB = -12 V	2N2944A	IEBO		-0.1	ηΑ
VEB = -20 V VEB = -32 V	2N2945A 2N2946A			-0.2 -0.5	
ON CHARACTERISTICS: (1)	ZINZ940A			-0.5	
Forward-Current Transfer Ratio					
$I_C = -1.0 \text{ mA}, V_{CE} = -0.5 \text{ V}$	2N2944A	hFE	100		
IC = -1.0 IIIA, VCE = -0.5 V	2N2944A 2N2945A	"""	70		
	2N2946A		50		
Forward-Current Transfer Ratio (inverted conne					
$I_E = -200 \mu A$ , $V_{EC} = -0.5 \text{ V}$	2N2944A	hFE(inv)	50		
[ε - 200 μπ, νες - 0.0 ν	2N2945A	. =()	30		
	2N2946A		20		
Emitter-Collector Offset Voltage					
$I_B = -200  \mu A, I_F = 0$	2N2944A	VEC(ofs)		-0.3	mV
	2N2945A	, ,		-0.5	
	2N2946A			-0.8	
$I_B = -1.0 \text{ mA}, I_E = 0$	2N2944A			-0.6	
	2N2945A			-1.0	
	2N2946A			-2.0	
$I_B = -2.0 \text{ mA}, I_E = 0$	2N2944A			-1.0 -1.6	
	2N2945A			-1.6	
	2N2946A			-2.5	
DYNAMIC CHARACTERISTICS:		<b>T</b>		1	ı
Emitter-Collector On-State Resistance					
$I_B = -100 \mu A$ , $I_E = 0$ , $I_e = 100 \mu A$ ac (rms)	2N2944A	r <sub>ec</sub> (on)		10	
f = 1.0 kHz	2N2945A			12	
10 m\	2N2946A 2N2944A			14 4.0	Ω
$I_B = -1.0 \text{ mA}, I_E = 0, I_e = 100 \mu\text{A} \text{ ac (rms)}$ f = 1.0  kHz	2N2945A			6.0	
I = 1.0 KHZ	2N2946A			8.0	
Magnitude of Small-Signal Forward				0.0	
Current Transfer Ratio	2N2944A	h <sub>fe</sub>	15	55	
$I_C = -1.0 \text{ mA}, V_{CE} = -6.0 \text{V}, f = 1.0 \text{ MHz}$	2N2945A	1.161	10	55	
10 - 1.0 11/14, VCE - 0.0 V, 1 - 1.0 1VII 12	2N2946A		5.0	55	
Output Capacitance					_
$V_{CB} = -6.0 \text{ V}, I_E = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz}$		C <sub>obo</sub>		10	pF
Input Capacitance					
$V_{EB} = -6.0 \text{ V}, I_{C} = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz}$		C <sub>ibo</sub>		6.0	pF
VED - 0.0 V, IO - 0, 100 KIZ - 1 - 1.0 WILZ		i	ĺ	1	l

<sup>(1)</sup> Pulse Test: Pulse Width = 300 s, duty cycle 2.0%.



## **GRAPHS**

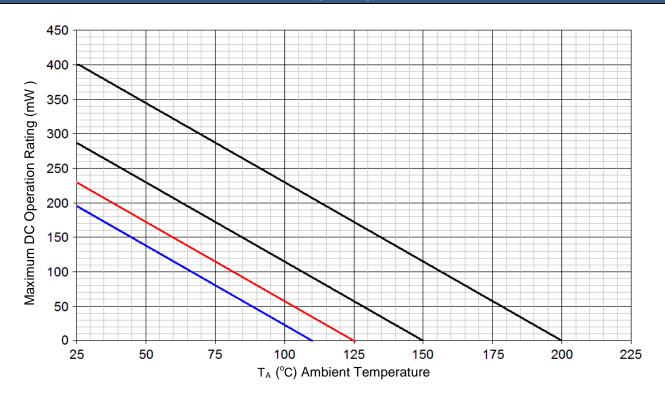
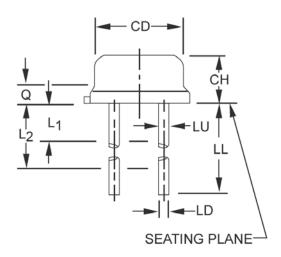
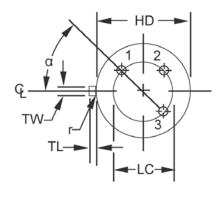


FIGURE 1 – Temperature-Power Derating Curve



## **PACKAGE DIMENSIONS**





	Dimensions					
Ltr.	Inc	ches	Millimeters		Notes	
	Min	Max	Min	Max		
CD	.178	.195	4.52	4.95		
СН	.065	.085	1.65	2.16		
HD	.209	.230	5.31	5.84		
LC	.10	0 TP	2.54 TP		5	
LD	.016	.021	0.41	0.53		
LL	.500	1.750	12.70	44.45	6	
LU	.016	.019	0.41	0.48	6	
L1		.050		1.27	6	
L2	.250		6.35		6	
Q		.040		1.02	3	
TL	.028	.048	0.71	1.22	8	
TW	.036	.046	0.91	1.17	4	
r		.010		0.25	9	
a.	45	° TP	45°	<sup>¬</sup> TP	5	

#### NOTES:

- 1. Dimensions are in inches.
- Millimeters are given for general information only.
   Symbol TL is measured from HD maximum.
- 4. Details of outline in this zone are optional.
- 5. Leads at gauge plane .054 inch (1.37 mm) +.001 inch (0.03 mm) -.000 inch (0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of TP relative to tab. Device may be measured by direct methods or by gauge.
- 6. Symbol LU applies between L<sub>1</sub> and L<sub>2</sub>. Dimension LD applies between L<sub>2</sub> and LL minimum.
- 7. Lead number three is electrically connected to case.
- 8. Beyond r maximum, TW shall be held for a minimum length of .011 inch (0.28 mm).
- 9. Symbol r applied to both inside corners of tab.
- 10. In accordance with ASME Y14.5M, diameters are equivalent to  $\Phi x$  symbology.
- 11. Lead 1 is emitter, lead 2 is base, and lead 3 is collector.